# Everspin nvNITRO<sup>™</sup> Storage Accelerator U.2 ES1GB-U201

#### **Product Brief**





Accelerate your enterprise compute and storage systems with full data integrity on power failure and virtually unlimited endurance using Everspin nvNITRO<sup>™</sup> Accelerators

**BLAZING FAST PERFORMANCE** 750K+ IOPS and 7 µS Latency (4K Random Read/Write with End-End latency)

TWO ACCESS MODES NVMe SSD and Direct Access (MMIO)







Power Fail Safe No Batteries or Super-Caps needed

Unlimited Endurance Just keeps going 1,000,000,000 cycles

No Power Cycle Wait Zero data flush, recovery or charge time





Full Performance Across entire thermal profile

### Highlights

- 1GB Storage Capacity
- PCle Gen3 x4
- U.2 2.5" form factor
- NVMe 1.2.1 in block mode
- Memory mapped IO (MMIO) in byte mode
- Ultra-low access latency (uS)
- Consistent latency (short tail)
- Customer defined features using own RTL
  with programmable FPGA
- Development license for NVMe core IP

### **Applications**

- Power Fail Safe Data & Metadata Cache/Buffer
- Burst Data Deserializer
- Database and Application Accelerators
- Storage Accelerator For All Flash Storage Array (FSA)
- File System Accelerator (Parallel & Serial)
- Power Fail Safe Software Defined Storage
- Power Fail Safe Software And NVMe RAID
- OLTP Log Cache Acceleration
- Storage Fabric (Network) Accelerators
- Shared Remote Persistent Memory

## **Key Specifications**

Category	Parameter	Specification (Preliminary)
	Available Capacity	1GB
	Component	256Mb Perpendicular ST-MRAM
Performance	Sequential Read / Write	Up to 3,000 MB/sec
	Random 4KB Read	Up to 730,000 MB/sec
	Random 4KB Write	Up to 750,000 IOPS
	Sustained 4KB Write	Up to 750,000 IOPS
	Random 70/30 Read/Write	Up to 730,000 IOPS
	Average Latency Read/Write (QD1)	7 μsec (Read), 8 μsec (Write)
	Worst Case Latency Read/Write (QD8)	11 μsec (Read), 12 μsec (Write)
Endurance	Drive Writes per Day	Unlimited Uniform Access
	Data Retention	Power On - Infinite, Power Off - 3 Months at 50°C
	Warranty	5 years
Interface	Host Interface Non-volatile Memory Ex- press (NVMe)	PCle Gen3 x4 (4GT/s)
	Form Factor	U.2, 2.5 inches
	Access Modes	Block Mode (NVMe), Direct Byte Access (MMIO)
	Weight	125g
Environment	Power Consumption 70/30 Read/Write	< 25W
	Operating Temperature	0 to 55°C ambient with suggested airflow
	Non-operating Temperature	-40°C to +70°C
	Airflow (Min)	300 LFM
OS	Linux, Windows	
Management	Self Monitoring Analysis and Reporting Technology (SMART ) Commands	
Customization	Customers may optionally program onboard FPGA with own RTL to extend features / functions	

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